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Complete if Known	<u></u>
Application Number	10/052,952
Filing Date	January 17, 2002
First Named Inventor	Forbes, Leonard
Group Art Unit	2874
Examiner Name	Unknown

Sheet 1 of 3 Attorney Docket No: 1303.034US1

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT	Application Number	10/052,952		
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Way , 28	Examiner Name	Unknown		
Sheet 2 of 3	Attorney Docket No: 1	303.034US1		

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Sheet 3 of 3		Attorney Docket No: 1	303.034US1
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